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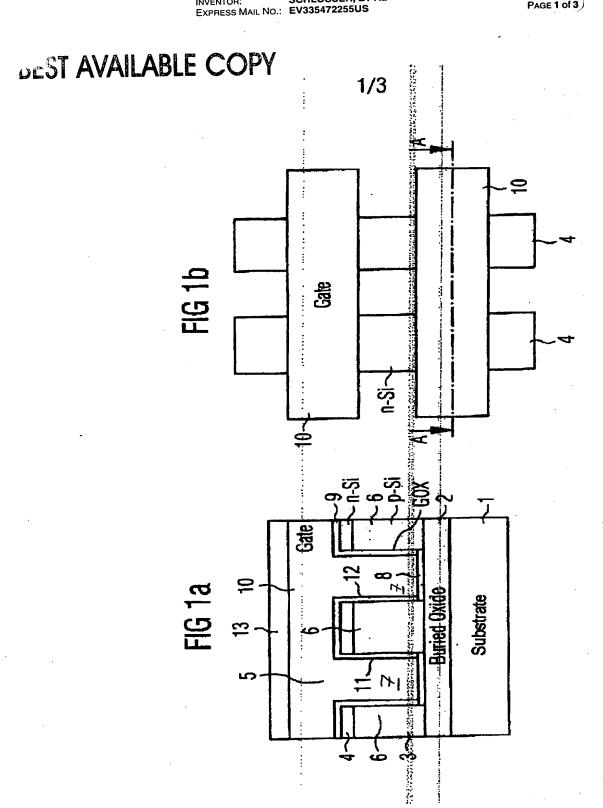
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APPLICANT:

HEREWITH
INFINEON TECHNOLOGIES, AG
DRAM CELL ARRANGEMENT WTH VERTICAL MOS
TRANSISTORS, AND METHOD FOR ITS FABRICATION
SCHLÖSSER, ET AL

INVENTOR:

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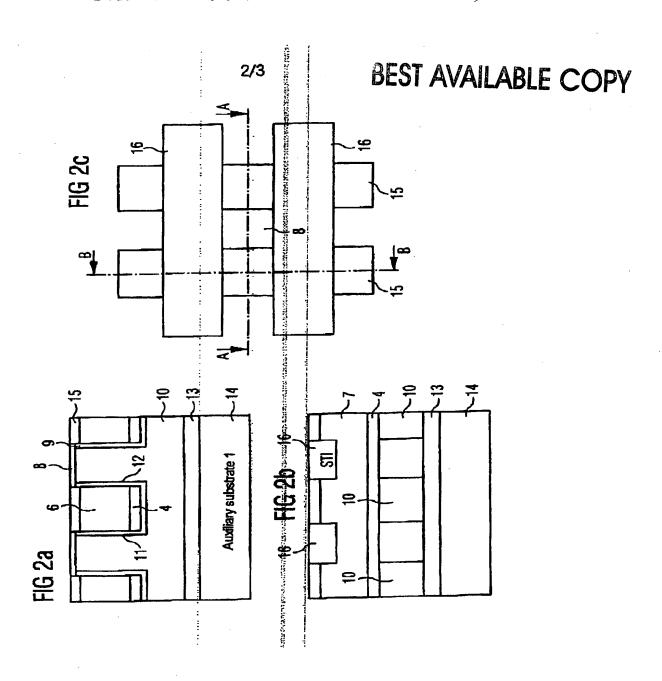
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TITLE: DRAM CELL ARRANGEMENT WTH VERTICAL MOS
TRANSISTORS, AND METHOD FOR ITS FABRICATION
INVENTOR: SCHLÖSSER, ET AL
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CONF. No.: UNKNOWN

INVENTOR:

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